

2A High-Speed MOSFET Drivers

Features

- Latch-Up Protected: Withstands 500 mA Reverse Current
- · Input Withstands Negative Inputs Up to 5V
- Electrostatic Discharge (ESD) Protected: 2.0 kV (HBM) and 400V (MM)
- · High Peak Output Current: 2A
- · Wide Input Supply Voltage Operating Range:
 - 4.5V to 16V
- · High Capacitive Load Drive Capability:
 - 1000 pF in 18 ns
- · Short Delay Time: 35 ns typical
- · Matched Delay Times
- · Low Supply Current:
 - With Logic '1' Input: 500 μA
 - With Logic '0' Input: 100 μA
- Low Output Impedance: 4Ω
- Available in Space-Saving 8-pin MSOP Package
- Pinout same as TC1410/TC1411/TC1413

Applications

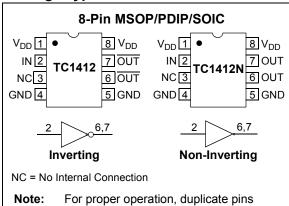
- Switch Mode Power Supplies
- · Pulse Transformer Drive
- Line Drivers
- · Relay Driver

General Description

The TC1412/TC1412N are 2A CMOS buffers/drivers. They do not latch up under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of current of either polarity being forced back into their output. All terminals are fully protected against electrostatic discharge (ESD) up to 2.0 kV (HBM) and 400V (MM).

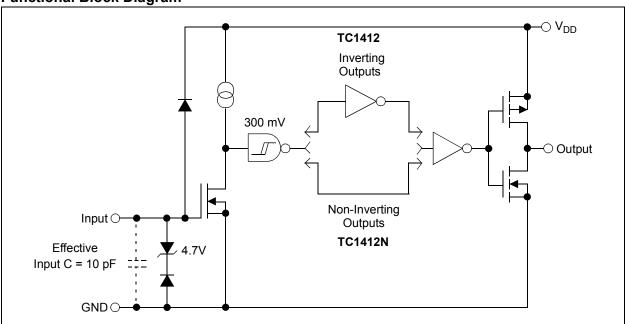
As MOSFET drivers, the TC1412/TC1412N can easily charge a 1000 pF gate capacitance in 18 ns with matched rise and fall times. To ensure that the MOSFET's intended state will not be affected even by large transients, low enough impedance in both the 'On' and 'Off' states are provided. The leading and trailing edge propagation delay times are also matched to allow driving short-duration inputs with greater accuracy.

Package Type



must be connected together.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

| Supply Voltage | +20V |
|---|------------------|
| Input VoltageV _{DD} + 0. | 3V to GND - 5.0V |
| Power Dissipation (T _A ≤ 70°C) | |
| MSOP | 340 mW |
| PDIP | 730 mW |
| SOIC | 470 mW |
| Storage Temperature Range | 65°C to +150°C |
| Maximum Junction Temperature | +150°C |

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

| Parameters | Sym. | Min. | Тур. | Max. | Units | Conditions |
|---|------------------|-------------------------|------|----------|-------|--|
| Input | - | | | • | | |
| Logic '1', High Input Voltage | V _{IH} | 2.0 | _ | _ | V | |
| Logic '0', Low Input Voltage | V _{IL} | _ | _ | 0.8 | V | |
| Input Current | I _{IN} | -1.0 | _ | 1.0 | μA | $0V \le V_{IN} \le V_{DD}, T_A = +25^{\circ}C$ |
| | | -10 | _ | 10 | | $-40^{\circ}C \le T_A \le +85^{\circ}C$ |
| Output | | | | | | |
| High Output Voltage | V _{OH} | V _{DD} – 0.025 | _ | _ | V | DC Test |
| Low Output Voltage | V _{OL} | _ | _ | 0.025 | V | DC Test |
| Output Resistance | R _O | _ | 4 | 6 | Ω | V_{DD} = 16V, I_{O} = 10 mA, T_{A} = +25°C |
| | | _ | 5 | 7 | | $0^{\circ}C \leq T_A \leq +70^{\circ}C$ |
| | | _ | 5 | 7 | | $-40^{\circ}C \le T_A \le +85^{\circ}C$ |
| Peak Output Current | I _{PK} | _ | 2.0 | <u> </u> | Α | V _{DD} = 16V |
| Latch-Up Protection Withstand Reverse Current | I _{REV} | _ | 0.5 | _ | Α | Duty cycle \leq 2%, t \leq 300 µs, V_{DD} = 16V |
| Switching Time (Note 1) | • | | | • | • | |
| Rise Time | t _R | _ | 18 | 26 | ns | T _A = +25°C |
| | | _ | 20 | 31 | | $0^{\circ}C \le T_A \le +70^{\circ}C$ |
| | | _ | 22 | 31 | | -40°C ≤ T _A ≤ +85°C, Figure 4-1 |
| Fall Time | t _F | _ | 18 | 26 | ns | T _A = +25°C |
| | | _ | 20 | 31 | | $0^{\circ}C \leq T_A \leq +70^{\circ}C$ |
| | | _ | 22 | 31 | | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$, Figure 4-1 |
| Delay Time | t _{D1} | _ | 35 | 45 | ns | T _A = +25°C |
| | | _ | 40 | 50 | | $0^{\circ}C \leq T_A \leq +70^{\circ}C$ |
| | | | 40 | 50 | | $-40^{\circ}C \le T_A \le +85^{\circ}C$, Figure 4-1 |
| Delay Time | t _{D2} | | 35 | 45 | ns | T _A = +25°C |
| | | | 40 | 50 | | $0^{\circ}C \le T_A \le +70^{\circ}C$ |
| | | _ | 40 | 50 | | -40°C ≤ T _A ≤ +85°C, Figure 4-1 |

Note 1:Switching times ensured by design.

DC CHARACTERISTICS (CONTINUED)

| Electrical Specifications: Unless otherwise noted, $T_A = +25^{\circ}C$, with $4.5V \le V_{DD} \le 16V$. | | | | | | | | |
|---|----------------|---|-----|------|----|---|--|--|
| Parameters Sym. Min. Typ. Max. Units Conditions | | | | | | | | |
| Power Supply | Power Supply | | | | | | | |
| Power Supply Current | I _S | _ | 0.5 | 1.0 | mA | V _{IN} = 3V, V _{DD} = 16V | | |
| | | _ | 0.1 | 0.15 | | V _{IN} = 0V | | |

Note 1:Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

| Parameters | Sym. | Min. | Тур. | Max. | Units | Conditions | |
|---------------------------------|-------------------|------|-------|------|-------|------------|--|
| Temperature Ranges | | | | | | | |
| Specified Temperature Range (C) | T _A | 0 | _ | +70 | °C | | |
| Specified Temperature Range (E) | T _A | -40 | _ | +85 | °C | | |
| Maximum Junction Temperature | T _J | _ | _ | +150 | °C | | |
| Storage Temperature Range | T _A | -65 | _ | +150 | °C | | |
| Package Thermal Resistances | | | | | | | |
| Thermal Resistance, 8L-MSOP | θ_{JA} | _ | 211 | _ | °C/W | | |
| Thermal Resistance, 8L-PDIP | θ_{JA} | _ | 89.3 | _ | °C/W | | |
| Thermal Resistance, 8L-SOIC | $\theta_{\sf JA}$ | _ | 149.5 | _ | °C/W | | |

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, over operating temperature range with $4.5 \text{V} \leq \text{V}_{DD} \leq 16 \text{V}$.

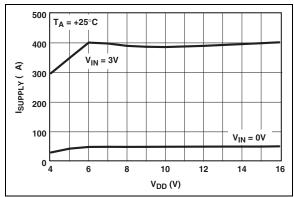


FIGURE 2-1: Quiescent Supply Current vs. Supply Voltage.

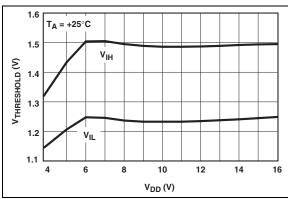


FIGURE 2-2: Input Threshold vs. Supply Voltage.

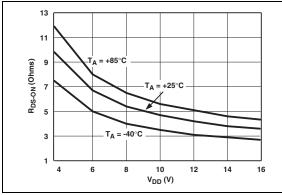


FIGURE 2-3: High State Output Resistance vs. Supply Voltage.

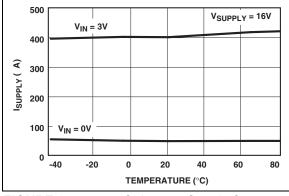


FIGURE 2-4: Quiescent Supply Current vs. Temperature.

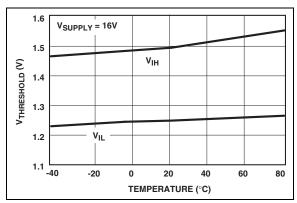


FIGURE 2-5: Input Threshold vs. Temperature.

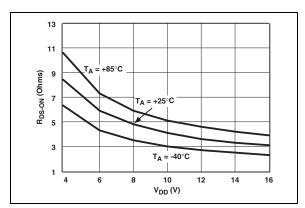


FIGURE 2-6: Low State Output Resistance vs. Supply Voltage.

Note: Unless otherwise indicated, over operating temperature range with $4.5V \le V_{DD} \le 16V$.

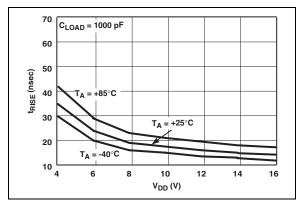


FIGURE 2-7: Rise Time vs. Supply Voltage.

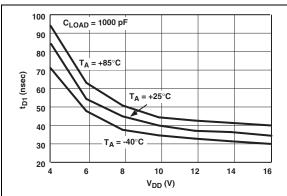


FIGURE 2-8: Propagation Delay vs. Supply Voltage.

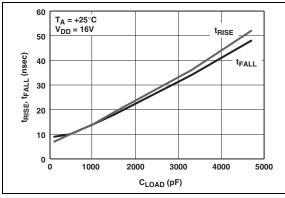


FIGURE 2-9: Rise and Fall Times vs. Capacitive Load.

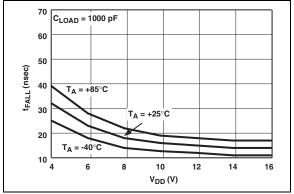


FIGURE 2-10: Fall Time vs. Supply Voltage.

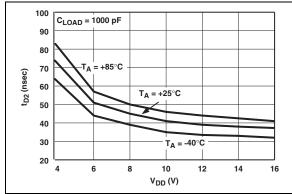


FIGURE 2-11: Propagation Delay vs. Supply Voltage.

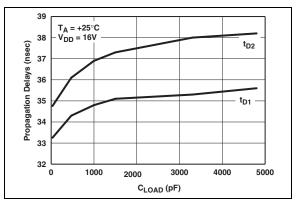


FIGURE 2-12: Propagation Delays vs. Capacitive Load.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

| Pin No. | TC1412 MSOP, PDIP, SOIC | TC1412N MSOP, PDIP, SOIC | Description |
|------------|----------------------------|-----------------------------|--|
| 1 | V_{DD} | V_{DD} | Supply input, 4.5V to 16V |
| 2 | IN | IN | Control input |
| 3 | NC | NC | No connection |
| 4 | GND | GND | Ground |
| 5 | GND | GND | Ground |
| 6 | OUT | OUT | CMOS push-pull output, common to pin 7 |
| 7 | OUT | OUT | CMOS push-pull output, common to pin 6 |
| 8 | V_{DD} | V_{DD} | Supply input, 4.5V to 16V |

3.1 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 16V with respect to the ground pin. The V_{DD} input should be bypassed to ground with a local ceramic capacitor. The value of the capacitor is chosen based on the capacitive load that is being driven. A value of 1.0 μ F is suggested.

3.2 Control Input (IN)

The MOSFET driver input is a high-impedance, TTL/CMOS-compatible input. The input has 300 mV of hysteresis between the high and low thresholds which prevents output glitching even when the rise and fall time of the input signal is very slow.

3.3 CMOS Push-Pull Output (OUT, OUT)

The MOSFET driver output is a low-impedance, CMOS push-pull style output, capable of driving a capacitive load with 2A peak currents.

3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high peak currents that discharge the load capacitor. The ground pins should be tied into a ground plane or have very short traces to the bias supply source return.

3.5 No Connect (NC)

No internal connection.

4.0 APPLICATION INFORMATION

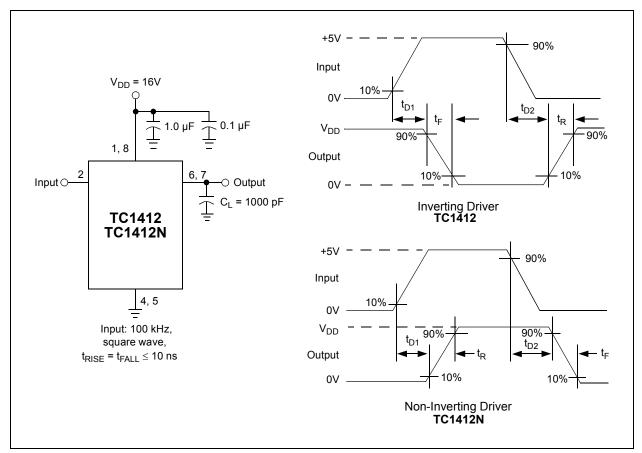
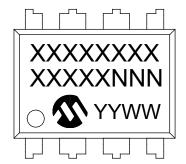


FIGURE 4-1: Switching Time Test Circuit.

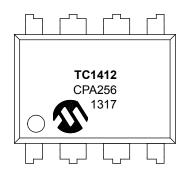
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

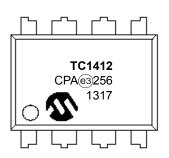
8-Lead PDIP (300 mil)







OR



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

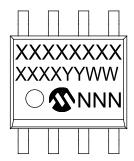
e3 RoHS Compliant JEDEC® designator for Matte Tin (Sn)

This package is RoHS Compliant. The RoHS Compliant JEDEC designator ((e3))

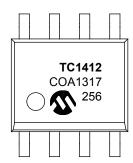
can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

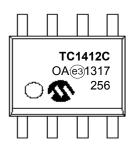
8-Lead SOIC (3.90 mm)



Example



OR



8-Lead MSOP (3x3 mm)

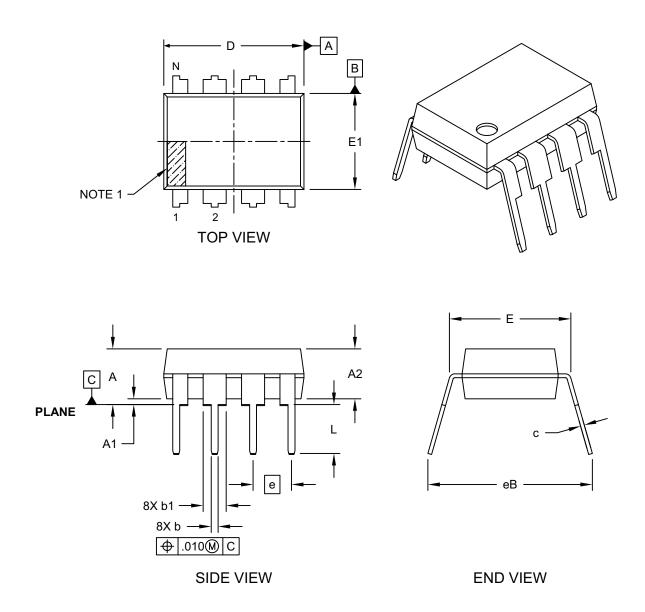


Example



8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

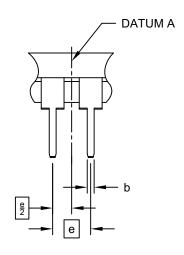
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



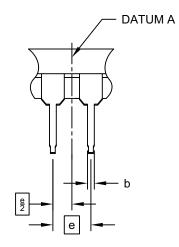
Microchip Technology Drawing No. C04-018D Sheet 1 of 2

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



ALTERNATE LEAD DESIGN (VENDOR DEPENDENT)



| | | INCHES | | | |
|----------------------------|----------|----------------|----------|------|--|
| Dimension | n Limits | MIN | NOM | MAX | |
| Number of Pins | N | | 8 | | |
| Pitch | е | | .100 BSC | | |
| Top to Seating Plane | Α | • | - | .210 | |
| Molded Package Thickness | A2 | .115 | .130 | .195 | |
| Base to Seating Plane | A1 | .015 | - | - | |
| Shoulder to Shoulder Width | Е | .290 | .310 | .325 | |
| Molded Package Width | E1 | .240 | .250 | .280 | |
| Overall Length | D | .348 | .365 | .400 | |
| Tip to Seating Plane | L | .115 | .130 | .150 | |
| Lead Thickness | С | .008 | .010 | .015 | |
| Upper Lead Width | b1 | .040 | .060 | .070 | |
| Lower Lead Width | b | .014 .018 .022 | | | |
| Overall Row Spacing § | eB | - | - | .430 | |

Notes:

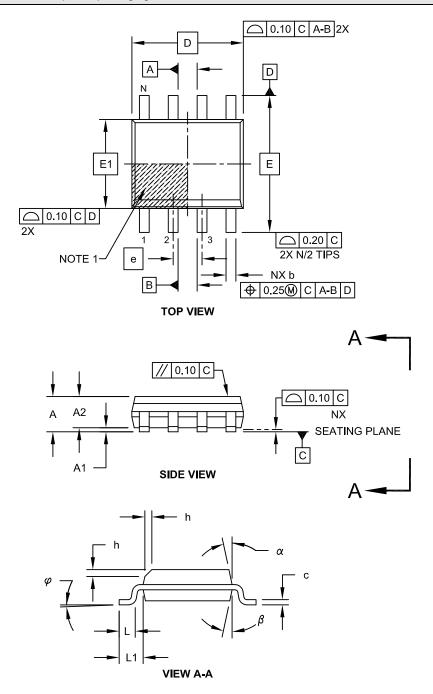
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-018D Sheet 2 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

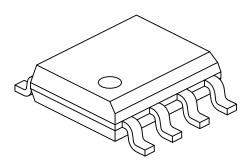
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057C Sheet 1 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | MILLIMETERS | | | | |
|--------------------------|-------------|-------------|----------|------|--|
| Dimension | Limits | MIN | NOM | MAX | |
| Number of Pins | N | 8 | | | |
| Pitch | е | | 1.27 BSC | | |
| Overall Height | Α | ı | ı | 1.75 | |
| Molded Package Thickness | A2 | 1.25 | ı | - | |
| Standoff § | A1 | 0.10 | ı | 0.25 | |
| Overall Width | Е | 6.00 BSC | | | |
| Molded Package Width | E1 | 3.90 BSC | | | |
| Overall Length | D | 4.90 BSC | | | |
| Chamfer (Optional) | h | 0.25 | i | 0.50 | |
| Foot Length | L | 0.40 | ı | 1.27 | |
| Footprint | L1 | | 1.04 REF | | |
| Foot Angle | φ | 0° | i | 8° | |
| Lead Thickness | С | 0.17 - 0.25 | | | |
| Lead Width | b | 0.31 | | 0.51 | |
| Mold Draft Angle Top | α | 5° | ı | 15° | |
| Mold Draft Angle Bottom | β | 5° | | 15° | |

Notes

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

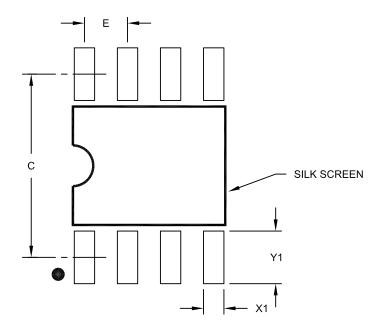
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| | Units | | | S | |
|-------------------------|------------------|----------|------|------|--|
| Dimension | Dimension Limits | | | MAX | |
| Contact Pitch | Е | 1.27 BSC | | | |
| Contact Pad Spacing | C | | 5.40 | | |
| Contact Pad Width (X8) | X1 | | | 0.60 | |
| Contact Pad Length (X8) | Y1 | | | 1.55 | |

Notes:

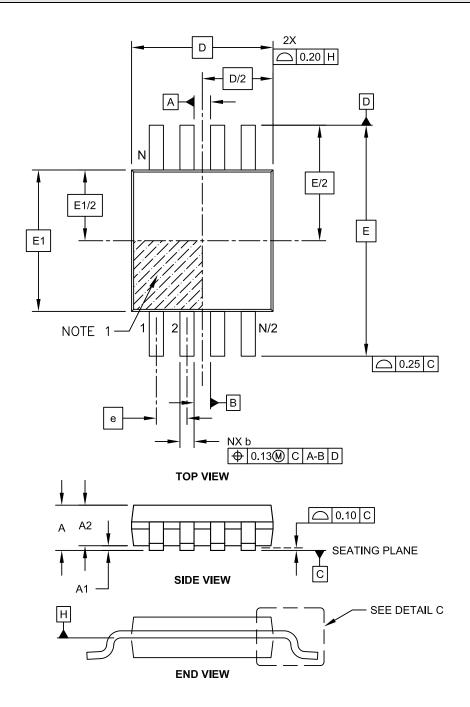
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

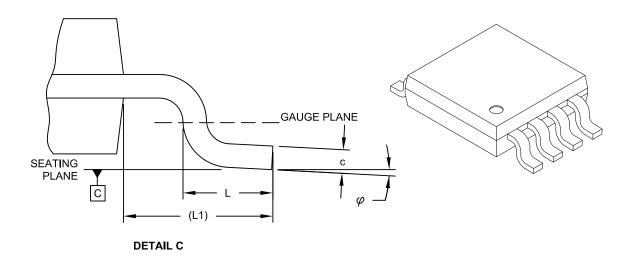
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | MILLIMETERS | | | | |
|--------------------------|-------------|----------|----------|------|--|
| Dimension | Limits | MIN | NOM | MAX | |
| Number of Pins | N | 8 | | | |
| Pitch | е | | 0.65 BSC | | |
| Overall Height | Α | - | - | 1.10 | |
| Molded Package Thickness | A2 | 0.75 | 0.85 | 0.95 | |
| Standoff | A1 | 0.00 | - | 0.15 | |
| Overall Width | Е | 4.90 BSC | | | |
| Molded Package Width | E1 | | 3.00 BSC | | |
| Overall Length | D | | 3.00 BSC | | |
| Foot Length | L | 0.40 | 0.60 | 0.80 | |
| Footprint | L1 | 0.95 REF | | | |
| Foot Angle | φ | 0° | - | 8° | |
| Lead Thickness | С | 0.08 | - | 0.23 | |
| Lead Width | b | 0.22 | - | 0.40 | |

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

3. Dimensioning and tolerancing per ASME Y14.5M.

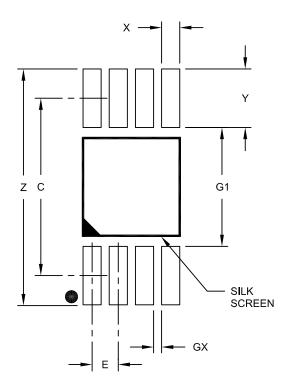
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| | Units | | | S |
|-------------------------|-------|----------|------|------|
| Dimension | MIN | NOM | MAX | |
| Contact Pitch | Е | 0.65 BSC | | |
| Contact Pad Spacing | С | | 4.40 | |
| Overall Width | Z | | | 5.85 |
| Contact Pad Width (X8) | X1 | | | 0.45 |
| Contact Pad Length (X8) | Y1 | | | 1.45 |
| Distance Between Pads | G1 | 2.95 | | |
| Distance Between Pads | GX | 0.20 | | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

APPENDIX A: REVISION HISTORY

Revision E (February 2015)

The following is the list of modifications:

- Updated the values for electrostatic discharge (ESD) in the Features and General Description columns.
- Updated the Pin Description table in Section 3.0, Pin Descriptions.
- Updated package marking information and drawings in Section 5.0, Packaging Information.
- Minor grammatical and spelling corrections.

Revision D (December 2012)

· Added a note to each package outline drawing.

Revision C (March 2003)

· Undocumented changes.

Revision B (May 2002)

• Undocumented changes.

Revision A (March 2001)

· Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

 $\underline{\text{To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.}\\$

| PART NO. | <u>X</u> /XX | Exa | amples: | |
|--------------------|---|-----|---------------|---|
| Device | Temperature Package Range | a) | TC1412COA: | 2A Single MOSFET driver, SOIC package, 0°C to +70°C. |
| Device: | TC1412: 2 A Single MOSFET Driver, Inverting TC1412N: 2 A Single MOSFET Driver, Non-Inverting | b) | TC1412CPA: | 2A Single MOSFET driver, PDIP package, 0°C to +70°C. |
| Temperature Range: | C = 0°C to +70°C E = -40°C to +85°C | c) | TC1412EUA713: | Tape and Reel, 2A Single MOSFET driver, MSOP package, -40°C to +85°C. |
| Package: | OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel) UA = Plastic Micro Small Outline (MSOP), 8-lead * UA713 = Plastic Micro Small Outline (MSOP), 8-lead * | a) | TC1412NCPA: | 2A Single MOSFET |
| | (Tape and Reel) PA = Plastic DIP (300 mil Body), 8-lead * MSOP package is only available in E-Temp. | b) | TC1412NEPA: | driver, PDIP package, 0°C to +70°C. 2A Single MOSFET driver, PDIP package, |
| | | c) | TC1412NEUA: | -40°C to +85°C. 2A Single MOSFET driver, MSOP package, -40°C to +85°C. |

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the
 intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
 knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, flexPWR, JukeBlox, KEELoQ, KEELoQ logo, Kleer, LANCheck, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC³² logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

The Embedded Control Solutions Company and mTouch are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, ECAN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, KleerNet, KleerNet logo, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, RightTouch logo, REAL ICE, SQI, Serial Quad I/O, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

 $\ensuremath{\mathsf{SQTP}}$ is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2001-2015, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-63277-092-9

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200

Fax: 480-792-7277 Technical Support:

http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI

Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis
Noblesville, IN

Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles Mission Viejo, CA

Tel: 949-462-9523 Fax: 949-462-9608

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110

Canada - Toronto Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office Suites 3707-14, 37th Floor

Tower 6, The Gateway Harbour City, Kowloon

Hong Kong

Tel: 852-2943-5100 Fax: 852-2401-3431

Australia - Sydney Tel: 61-2-9868-6733

Fax: 61-2-9868-6755 China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Dongguan Tel: 86-769-8702-9880

China - Hangzhou Tel: 86-571-8792-8115 Fax: 86-571-8792-8116

China - Hong Kong SAR Tel: 852-2943-5100 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829

Fax: 86-24-2334-2829

China - Shenzhen Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300

Fax: 86-27-5980-5118 **China - Xian** Tel: 86-29-8833-7252

Fax: 86-29-8833-7256

ASIA/PACIFIC

China - Xiamen Tel: 86-592-2388138

Fax: 86-592-2388138

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

India - Bangalore Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune Tel: 91-20-3019-1500

Japan - Osaka Tel: 81-6-6152-7160

Fax: 81-6-6152-9310 **Japan - Tokyo** Tel: 81-3-6880- 3770

Fax: 81-3-6880-3771 **Korea - Daegu** Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065

Fax: 63-2-634-9069 Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7828

Taiwan - Taipei Tel: 886-2-2508-8600

Fax: 886-2-2508-0102 **Thailand - Bangkok**Tel: 66-2-694-1351

Fax: 66-2-694-1350

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4450-2828

France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Fax: 45-4485-2829

Germany - Dusseldorf Tel: 49-2129-3766400

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Pforzheim Tel: 49-7231-424750

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Venice Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Poland - Warsaw Tel: 48-22-3325737

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820

01/27/15